

TECHNICAL DATA DATA SHEET 983, REV. -

# HERMETIC POWER SCHOTTKY RECTIFIER Very Low Forward Voltage Drop

**DESCRIPTION:** A 45 VOLT, 45 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC CERAMIC LCC-3P PACKAGE.

MAXIMUM RATINGS

### ALL RATINGS ARE @ $T_C = 25 \ ^{\circ}C$ UNLESS OTHERWISE SPECIFIED.

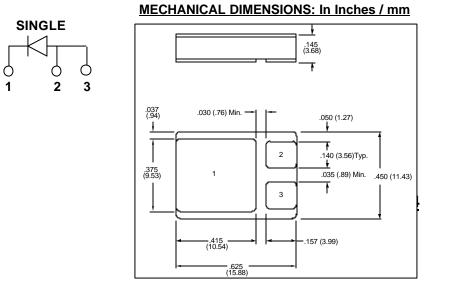
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	45	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100$ $^{\circ}C$ )	lo	45	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I <sub>FSM</sub>	200	Amps
MAXIMUM JUNCTION CAPACITANCE ( $V_r = 5V$ )	C <sub>T</sub>	2400	pF
MAXIMUM THERMAL RESISTANCE	$R_{ extsf{ heta}JC}$	0.47	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 150	°C

## **ELECTRICAL CHARACTERISTICS**

CHARACTERISTIC		SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (If	= 45 Amps)			
T <sub>J</sub> =	= 25 °C	V <sub>f</sub>	0.66	Volts
T <sub>J</sub> =	= 125 °C	vţ	0.57	
MAXIMUM REVERSE CURRENT (Ir @ 45V PIV)				
T <sub>J</sub> =	= 25 °C	l <sub>r</sub>	4.5	mA
T <sub>J</sub> =	= 125 °C		210	

# SENSITRON

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LCC-3P

### PINOUT TABLE

ТҮРЕ	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE



## **TECHNICAL DATA**

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